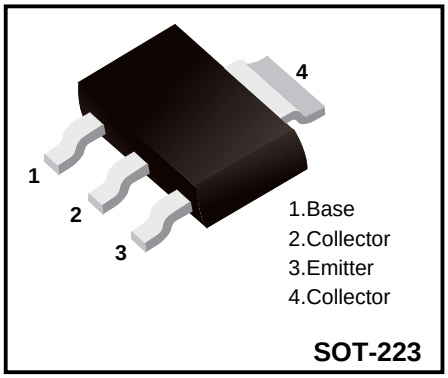
PNP Plastic-Encapsulate Transistors



Applications

- Telephone Switching Circuit
- Amplifier

Features

- High Collector-Emitter Voltage : BV_{CEO}=-150V
- High current gain

Absolute Maximum Ratings (Ta=25℃)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	BV_{CBO}	-160	V
Collector-Emitter Voltage	BV_{CEO}	-150	V
Emitter-Base Voltage	BV_{EBO}	-5	V
Collector Current	I_C	-600	mA
Collector Power Dissipation	P_C	2	W
Junction Temperature	Tj	150	℃
Storage Temperature	Tstg	-55～+150	℃

Electrical Characteristics (Ta=25℃)

Parameter	Symbol	Conditions	Value			Unit
			Min	Typ	Max	
Collector-base breakdown voltage	BV_{CBO}	I_C = -100μA, I_E = 0	-160			V
Collector-emitter breakdown voltage	BV_{CEO}	I_C = -1mA, I_B = 0	-150			V
Emitter-base breakdown voltage	BV_{EBO}	I_E = -100μA, I_C = 0	-5			V
Collector cut-off current	I_{CBO}	V_{CB} =-120V, I_E = 0			-50	nA
Emitter cut-off current	I_{EBO}	V_{EB} = -4V, I_C = 0			-50	nA
DC current gain	h_{FE}	V_{CE} = -5V, I_C= -1mA	80			
		V_{CE} = -5V, I_C= -10mA	80		400	
Collector-emitter saturation voltage	$V_{CE(sat)}$	I_C = -50mA, I_B = -5mA			-0.5	V
Base -emitter saturation voltage	$V_{BE(sat)}$	I_C =- 50mA, I_B =- 5mA			-1.0	V
Transition frequency	f_T	V_{CE} = -10V, I_B = -10mA	100			MH_Z
Output Capacitance	C_{ob}	V_{CB} =-10V,I_E = 0,f=1MHz			6	pF

Note: Pulse test: P W <300μs, Duty Cycle<2%

h_{FE} Classification

Classification	YFW5401-A	YFW5401-B	YFW5401-C
Range	80~170	150~240	200~400

Typical Characteristics

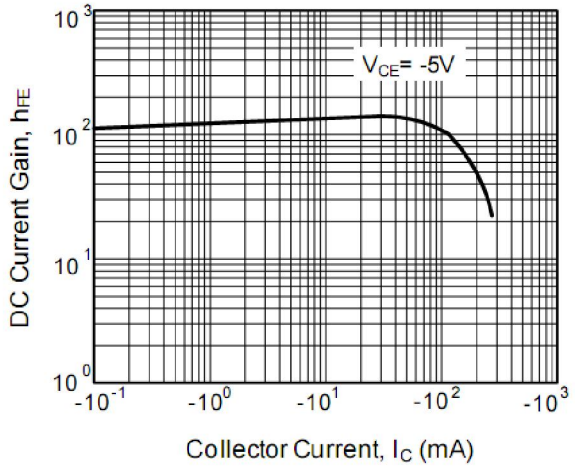


Figure 1. TDC Current Gain

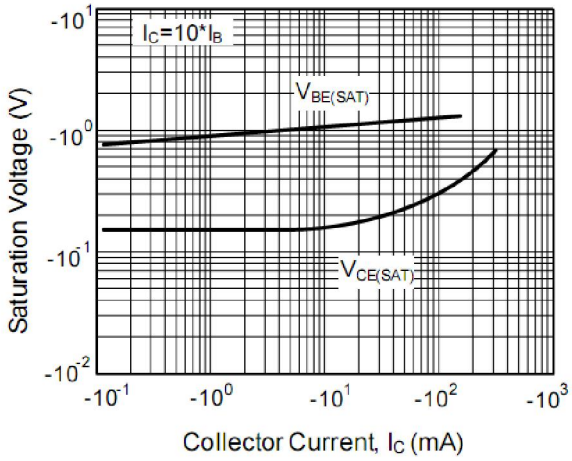


Figure 2. Saturation Voltage

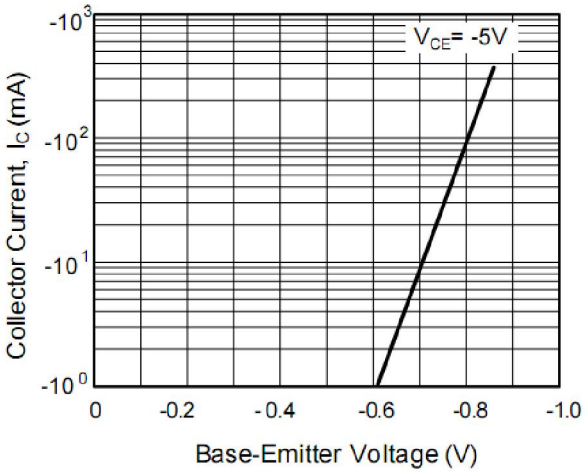


Figure 3. Base-Emitter on Voltage

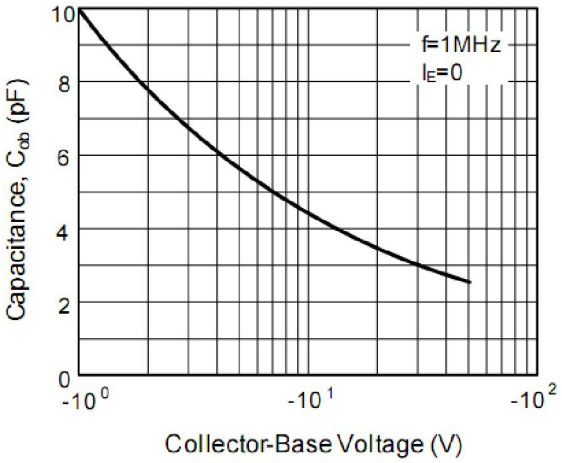


Figure 4. Collector Output Capacitance

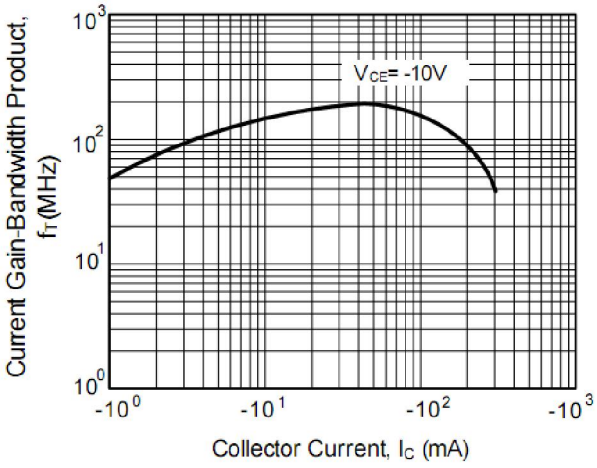


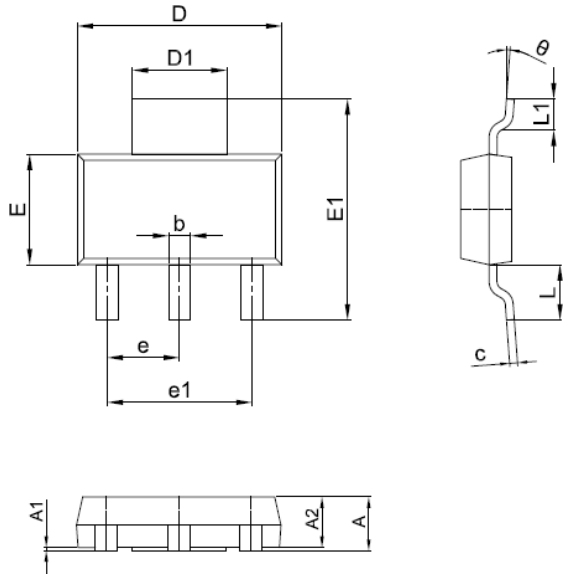
Figure 5. Current Gain-Bandwidth Product

Ordering information

Package	Packing Description	Base Quantity	Packing Quantity
SOT-223	Tape/Reel,7”reel	1000pcs/Reel	6000PCS/Box 30000PCS/Carton
	Tape/Reel,13”reel	2500pcs/Reel	5000PCS/Box 30000PCS/Carton

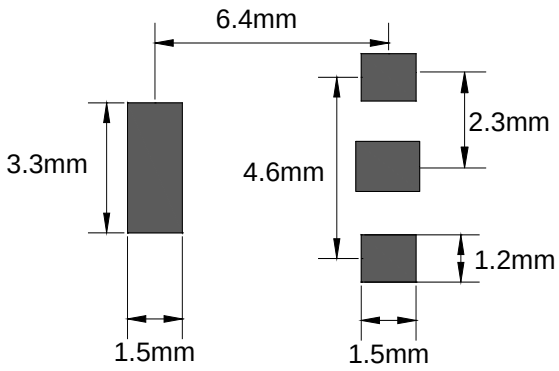
Package Dimensions

SOT-223



Dim	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	1.50	1.80	0.059	0.071
A1	0.00	0.10	0.000	0.004
A2	1.50	1.70	0.059	0.067
b	0.65	0.75	0.026	0.030
c	0.20	0.30	0.008	0.012
D	6.40	6.60	0.252	0.260
D1	2.90	3.10	0.114	0.122
E	3.30	3.70	0.130	0.146
E1	6.85	7.15	0.270	0.281
e	2.20	2.40	0.087	0.094
e1	4.40	4.80	0.173	0.189
L	1.65	1.85	0.065	0.073
L1	0.90	1.15	0.035	0.045

The recommended mounting pad size



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